NSN 5961-00-509-5812

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View Online at https://aerobasegroup.com/nsn/5961-00-509-5812 **Inclosure Material:** Plastic **Overall Length:** 0.570 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 collector to base voltage, dc and 100.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 15.00 amperes source cutoff current and 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 125.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: